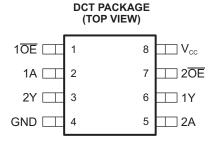


### FEATURES

- Available in the Texas Instruments NanoFree<sup>™</sup> Package
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V .
- Max t<sub>nd</sub> of 4.3 ns at 3.3 V
- Low Power Consumption, 10-µA Max I<sub>cc</sub>
- $\pm$ 24-mA Output Drive at 3.3 V ٠
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at  $V_{CC}$  = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> =  $25^{\circ}$ C



- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

I		ACKAGE VIEW)		YZP PACKAGE (BOTTOM VIEW)				
1 <u>0</u> €∏	1	8	⊥ V <sub>cc</sub>	GND		2A		
1A 🖂	2	7						
2Y □	3	6		1A	0270	20E		
	5	-		1 <del>0E</del>	0180	V <sub>CC</sub>		
GND 📖	4	5	2A			•		

See mechanical drawings for dimensions.

## **DESCRIPTION/ORDERING INFORMATION**

The SN74LVC2G125 is a dual bus buffer gate, designed for 1.65-V to 5.5-V V<sub>CC</sub> operation. This device features dual line drivers with 3-state outputs. The outputs are disabled when the associated output-enable (OE) input is high.

NanoFree<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(2)</sup>	
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74LVC2G125YZPR	CM_	
–40°C to 85°C	SSOP – DCT	Reel of 3000	SN74LVC2G125DCTR	C25	
-	Vesop Dell	Reel of 3000	SN74LVC2G125DCUR	005	
	VSSOP – DCU	Reel of 250	SN74LVC2G125DCUT	C25_	

#### **ORDERING INFORMATION**

Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at (1)www.ti.com/sc/package.

DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. (2)DCU: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.

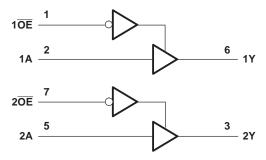
## SN74LVC2G125 **DUAL BUS BUFFER GATE** WITH 3-STATE OUTPUTS

SCES204M-APRIL 1999-REVISED JANUARY 2007

#### **FUNCTION TABLE** (EACH BUFFER)

INPU	JTS	OUTPUT
OE	Α	Y
L	Н	Н
L	L	L
Н	Х	Z

### LOGIC DIAGRAM (POSITIVE LOGIC)



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	6.5	V
VI	Input voltage range <sup>(2)</sup>		-0.5	6.5	V
Vo	Voltage range applied to any output in t	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high or low state <sup>(2)(3)</sup>				V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through V <sub>CC</sub> or GNI	)		±100	mA
		DCT package		220	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DCU package		227	°C/W
		YZP package		102	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(3) The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
(4) The package thermal impedance is calculated in accordance with JESD 51-7.

## Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
	Querra have a lite and	Operating	1.65	5.5	V
V <sub>CC</sub>	Supply voltage	Data retention only	1.5		V
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>		
V	Link level in subscriptions	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V
VIH	High-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$	2		V
		$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	$0.7 \times V_{CC}$		
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
V		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V
V <sub>IL</sub>	Low-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$		0.8	V
		$V_{CC} = 4.5 V \text{ to } 5.5 V$		$0.3 \times V_{CC}$	
VI	Input voltage		0	5.5	V
V <sub>O</sub> Output voltag	Output voltogo	High or low state	0	V <sub>CC</sub>	V
	Oulput voltage	3-state		5.5	v
		$V_{CC} = 1.65 V$		-4	
		V <sub>CC</sub> = 2.3 V		-8	
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 3 V		-16	mA
		$v_{\rm CC} = 3 v$		-24	
		$V_{CC} = 4.5 V$		-32	
		$V_{CC} = 1.65 V$		4	
		V <sub>CC</sub> = 2.3 V		8	
I <sub>OL</sub>	Low-level output current	$V_{CC} = 3 V$		16	mA
		$v_{CC} = 3 v$			
		$V_{CC} = 4.5 V$			
		$V_{CC}$ = 1.8 V $\pm$ 0.15 V, 2.5 V $\pm$ 0.2 V		20	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V
		$V_{CC}$ = 5 V ± 0.5 V		5	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## SN74LVC2G125 DUAL BUS BUFFER GATE WITH 3-STATE OUTPUTS

SCES204M-APRIL 1999-REVISED JANUARY 2007

#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

P	ARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP <sup>(1)</sup>	MAX	UNIT	
		I <sub>OH</sub> = -100 μA	1.65 V to 5.5 V	V <sub>CC</sub> – 0.1			
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2			
V	N/	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9		V	
V <sub>OH</sub>		I <sub>OH</sub> = -16 mA	- 3 V	2.4		v	
		$I_{OH} = -24 \text{ mA}$	3 V	2.3			
		I <sub>OH</sub> = -32 mA	4.5 V	3.8			
		I <sub>OL</sub> = 100 μA	1.65 V to 5.5 V		0.1		
		I <sub>OL</sub> = 4 mA	1.65 V		0.45		
V	V	I <sub>OL</sub> = 8 mA	2.3 V		0.3	V	
V <sub>OL</sub>		I <sub>OL</sub> = 16 mA	- 3 V		0.4	v	
		I <sub>OL</sub> = 24 mA	5 V		0.55		
		I <sub>OL</sub> = 32 mA	4.5 V		0.55		
I <sub>I</sub>	A or $\overline{\text{OE}}$ inputs	$V_{I} = 5.5 V \text{ or GND}$	0 to 5.5 V		±5	μΑ	
$I_{off}$		$V_{I} \text{ or } V_{O} = 5.5 \text{ V}$	0		±10	μA	
I <sub>OZ</sub>		$V_0 = 0$ to 5.5 V	3.6 V		10	μA	
$I_{CC}$		$V_{I} = 5.5 \text{ V or GND}, \qquad I_{O} = 0$	1.65 V to 5.5 V		10	μA	
$\Delta I_{\text{CC}}$		One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND	3 V to 5.5 V		500	μA	
Ci	Data inputs		3.3 V	3.5		рF	
U <sub>i</sub>	Control inputs	$V_{I} = V_{CC} \text{ or } GND$	5.5 V	4		Ы	
Co		$V_{O} = V_{CC}$ or GND	3.3 V	6.5		pF	

(1) All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

#### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER FROM (INPUT)		TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		$V_{CC}$ = 2.5 V ± 0.2 V		$V_{CC}$ = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
	(INFUT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	А	Y	3.3	9.1	1.5	4.8	1.4	4.3	1	3.7	ns
t <sub>en</sub>	ŌĒ	Y	4	9.9	1.9	5.6	1.2	4.7	1.2	3.8	ns
t <sub>dis</sub>	OE	Y	1.5	11.6	1	5.8	1.4	4.6	1	3.4	ns

### **Operating Characteristics**

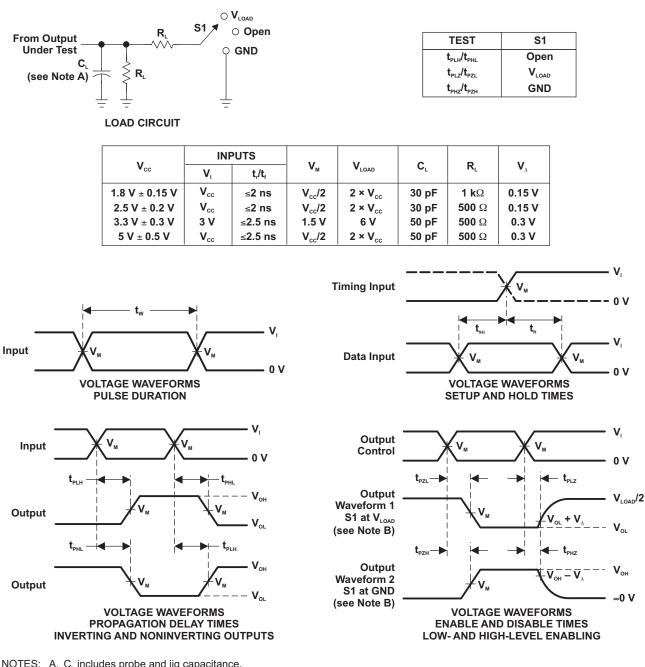
 $T_A = 25^{\circ}$ 

	PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	V <sub>CC</sub> = 5 V TYP	UNIT	
<u> </u>	Power dissipation	Outputs enabled	f = 10 MHz	19	19	20	22	рF	
C <sub>pd</sub>	capacitance	Outputs disabled		2	2	2	3	р <b>г</b>	

## SN74LVC2G125 **DUAL BUS BUFFER GATE** WITH 3-STATE OUTPUTS

SCES204M-APRIL 1999-REVISED JANUARY 2007

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_{L}$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>o</sub> = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{\mbox{\tiny PLZ}}$  and  $t_{\mbox{\tiny PHZ}}$  are the same as  $t_{\mbox{\tiny dis}}$
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{od}$ .
- H. All parameters and waveforms are not applicable to all devices.

#### Figure 1. Load Circuit and Voltage Waveforms

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#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
74LVC2G125DCTRE4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC2G125DCTRE6	ACTIVE	SM8	DCT	8	3000	Pb-Free (RoHS)	CU SNBI	Level-1-260C-UNLIM
74LVC2G125DCTRG4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC2G125DCURE4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC2G125DCURG4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC2G125DCUTE4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC2G125DCUTG4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G125DCTR	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G125DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G125DCUT	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G125YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN74LVC2G125 : • Automotive: SN74LVC2G125-Q1

NOTE: Qualified Version Definitions: • Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

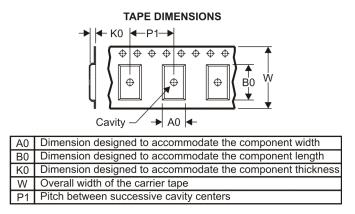
# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2G125DCUR	US8	DCU	8	3000	180.0	9.2	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC2G125YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1

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# PACKAGE MATERIALS INFORMATION

20-Jul-2010



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC2G125DCUR	US8	DCU	8	3000	202.0	201.0	28.0
SN74LVC2G125YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0

## **MECHANICAL DATA**

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

#### DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



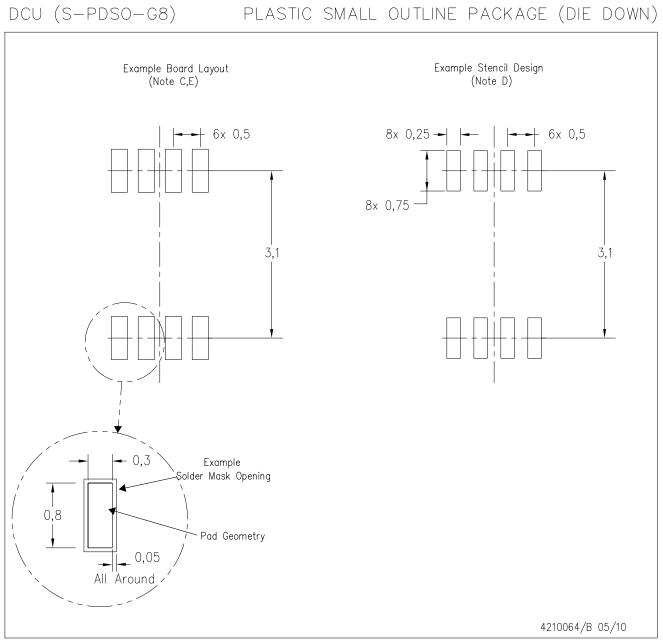
NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.





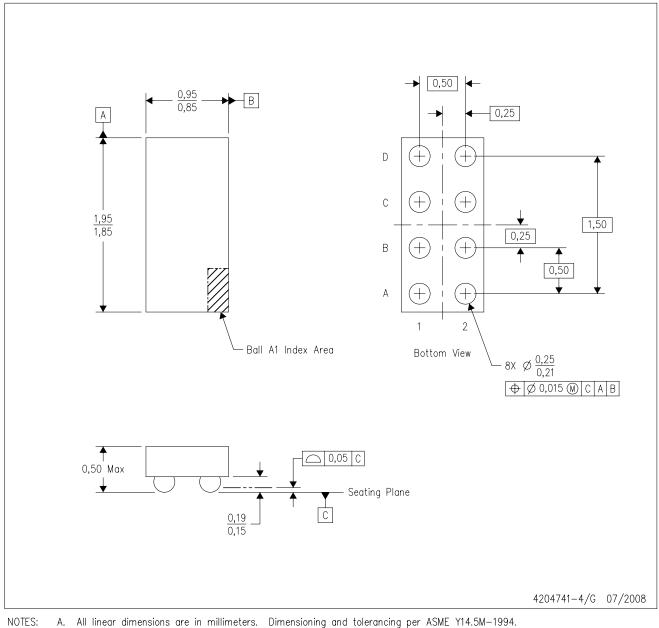
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead-free. Refer to the 8 YEP package (drawing 4204725) for tin-lead (SnPb).

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